AMENDMENTS TO THE CLAIMS

- 1. (Previously Presented) A method of producing a piezoelectric ceramic thick film on a substrate, said method comprising:
 - providing a piezoelectric ceramic material in powder form;
- forming a liquid mixture by mixing the powdered material with a liquid phase precursor of a metal oxide having a melting point lower than a temperature required for densifying the piezoelectric ceramic thick film by sintering, said precursor being adapted to decompose, upon subsequent annealing, into the metal oxide;
 - drying the liquid mixture to form a precipitate;
 - milling the precipitate to form a powdered precipitate;
 - adding an organic carrier to the powdered precipitate;
 - further milling the precipitate to form a paste;
 - depositing a layer of the paste, as a wet film, onto the substrate; and
- annealing the layered substrate at a temperature and for a time sufficient to cause transformation of the paste into the thick film.
- 2. (Original) A method according to claim 1, wherein the piezoelectric ceramic material is an inorganic ceramic material which exhibits the piezoelectric effect.

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3. (Original) A method according to claim 2, wherein the piezoelectric ceramic

material is lead zirconate titanate (PZT).

4. (Previously Presented) A method according to claim 1, wherein the metal oxide is

adapted to form a glass phase upon annealing at a temperature between 800° and 1000°C.

5-11. (Cancelled)

12. (Currently Amended) A method according to elaim 11 claim 1, wherein the

powdered piezoelectric material is fine-grained having an average grain size of below about

 $1.0 \mu m$.

13. (Original) A method according to claim 12, wherein the average grain size is

about 0.5µm.

14. (Previously Presented) A method according to claim 1, wherein the total amount

of the metal oxide in the thick film is between about 1% and 5%, by weight.

15. (Cancelled)

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16. (Previously Presented) A method according to claim 15, wherein the liquid mixture is dried at a temperature between 75° and 150°C to form a dried precipitate.

17. (Original) A method according to claim 16, wherein the liquid mixture is dried at a temperature between about 75°C and 105°C for up to 10 hours.

18. (Cancelled)

19. (Previously Presented) A method according to claim 1, wherein the powdered precipitate is formed by milling the dried precipitate with a ball mill.

20. (Cancelled)

- 21. (Previously Presented) A method according to claim 1, wherein the organic carrier is selected from one or more of ethyl cellulose, terpineol, and an organic binder containing texanol.
- 22. (Previously Presented) A method according to claim 21, wherein the organic carrier is the organic binder containing texanol.

23. (Cancelled)

- 24. (Previously Presented) A method according to claim 1, wherein the paste is deposited onto a surface of the substrate, by a printing process, as the wet film.
- 25. (Original) A method according to claim 24, wherein the printing process is a screen printing process.
- 26. (Previously Presented) A method according to claim 1, wherein, prior to annealing, the layered substrate including the deposited wet film is dried.
- 27. (Previously Presented) A method according to claim 1, wherein, prior to annealing, an isostatic pressure is applied to the film.
- 28. (Previously Presented) A method according to claim 26, wherein the drying temperature of the layered substrate including the deposited wet film is between about 20°C and about 175°C.
- 29. (Previously Presented) A method according to claim 1 wherein the layered substrate is annealed at a temperature of between about 820°C and about 950°C.
- 30. (Original) A method according to claim 29, wherein the annealing is conducted for between about 10 minutes and about 4 hours.

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31. (Previously Presented) A method according to claim 1, wherein the substrate is

formed of silicon.

32. (Previously Presented) A method according to claim 1, wherein the surface of the

substrate has a coating of platinum and the paste is deposited on this platinum coating.

33. (Previously Presented) A method according to claim 1, wherein a metal electrode

is formed on the piezoelectric ceramic thick film.

34. (Original) A method according to claim 33, wherein the metal is silver and the

electrode material is deposited on the film by a screen printing process.

35-38. (Cancelled)